
2SK2684(L), 2SK2684(S)

Silicon N Channel DV-L MOS FET
High Speed Power Switching

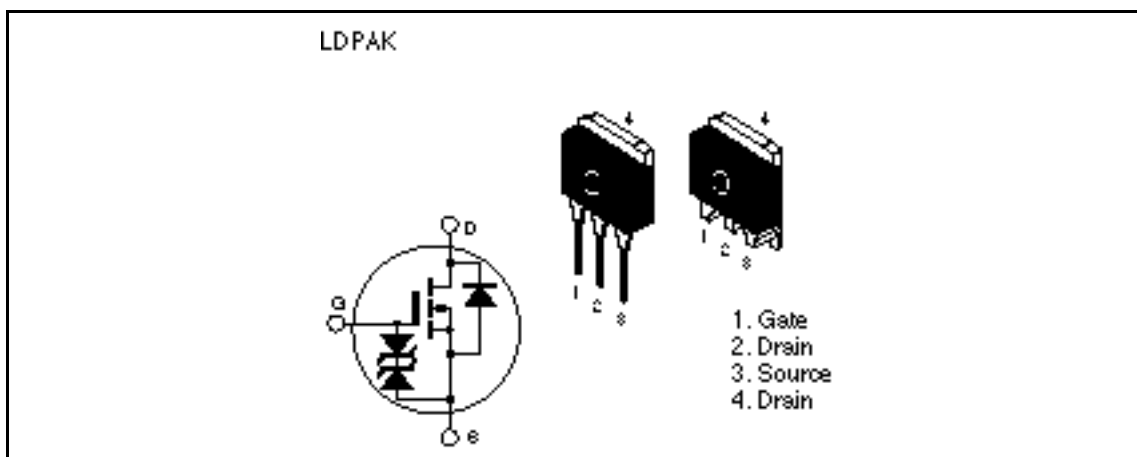
HITACHI

ADE-208-542
1st. Edition

Features

- Low on-resistance
 $R_{DS(on)} = 20 \text{ m}\Omega$ typ. ($V_{GS} = 10\text{V}$, $I_D = 15 \text{ A}$)
- 4V gate drive devices.
- High speed switching

Outline



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Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	30	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I_D	30	A
Drain peak current	$I_{D(pulse)}^{*1}$	120	A
Body to drain diode reverse drain current	I_{DR}	30	A
Channel dissipation	Pch ^{*2}	50	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW = 10μs, duty cycle = 1 %

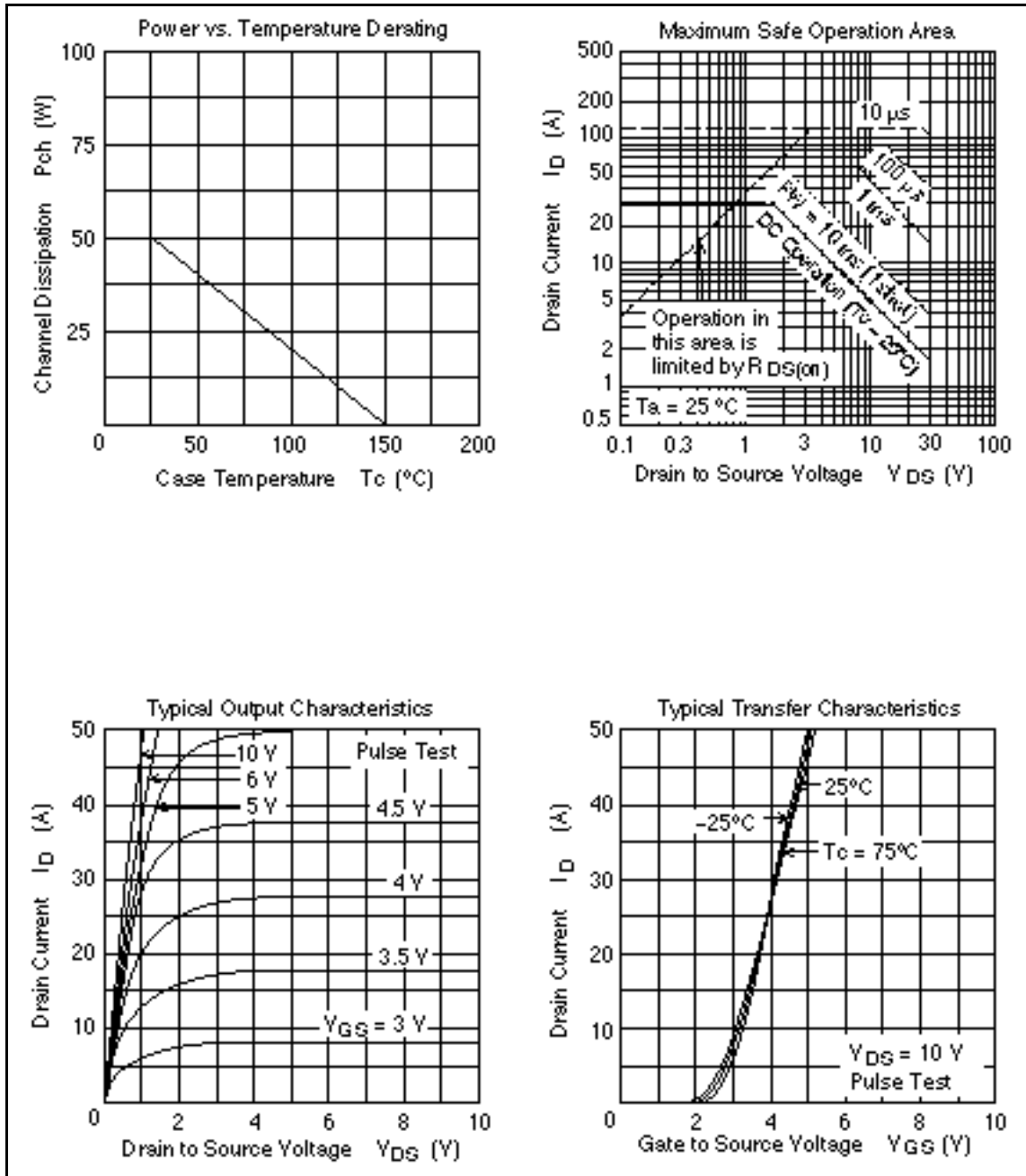
2. Value at Tc = 25°C

Electrical Characteristics (Ta = 25°C)

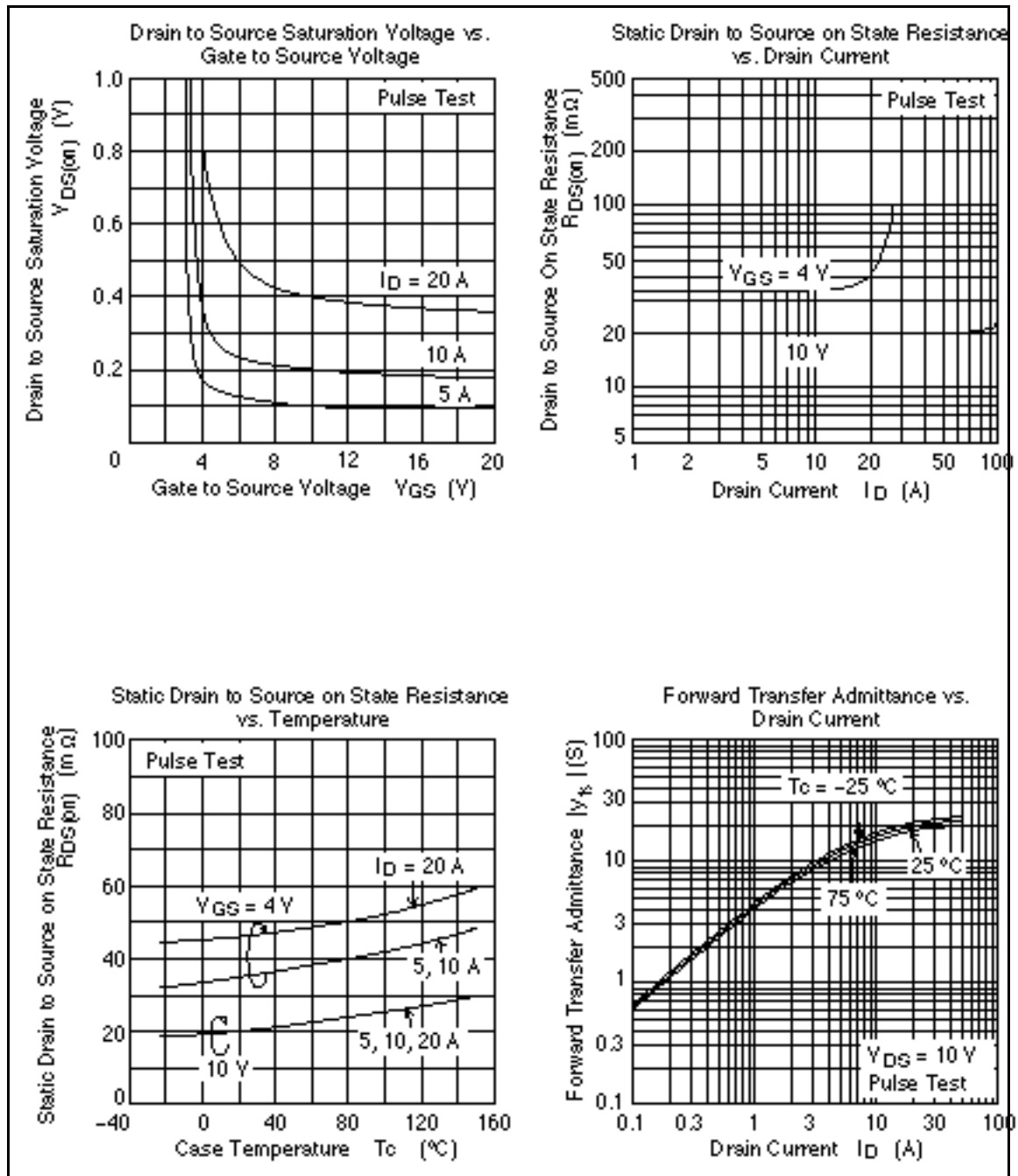
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	$I_D = 10mA, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	—	—	V	$I_G = ±100μA, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	10	μA	$V_{DS} = 30V, V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	±10	μA	$V_{GS} = ±16V, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	$I_D = 1mA, V_{DS} = 10V$
Static drain to source on state resistance	$R_{DS(on)}$	—	20	28	m	$I_D = 15A, V_{GS} = 10V^{*1}$
	$R_{DS(on)}$	—	35	50	m	$I_D = 15A, V_{GS} = 4V^{*1}$
Forward transfer admittance	$ y_{fs} $	12	18	—	S	$I_D = 15A, V_{DS} = 10V^{*1}$
Input capacitance	Ciss	—	750	—	pF	$V_{DS} = 10V$
Output capacitance	Coss	—	520	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	210	—	pF	f = 1MHz
Turn-on delay time	$t_{d(on)}$	—	16	—	ns	$V_{GS} = 10V, I_D = 15A$
Rise time	t_r	—	260	—	ns	$R_L = 0.67$
Turn-off delay time	$t_{d(off)}$	—	85	—	ns	
Fall time	t_f	—	90	—	ns	
Body to drain diode forward voltage	V_{DF}	—	1.0	—	V	$I_F = 30A, V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	45	—	ns	$I_F = 30A, V_{GS} = 0$ diF/ dt = 50A/μs

Note: 1. Pulse test

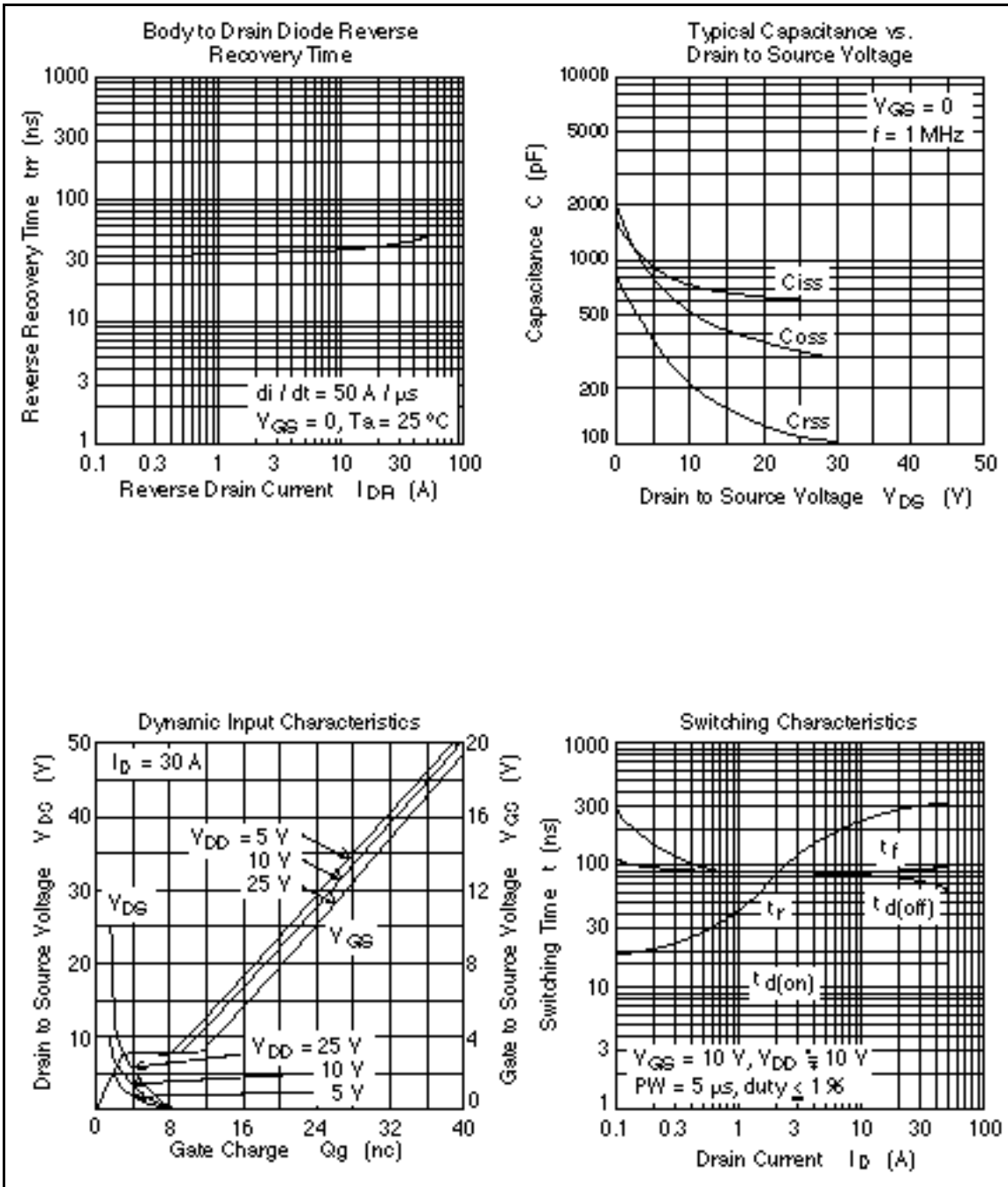
Main Characteristics



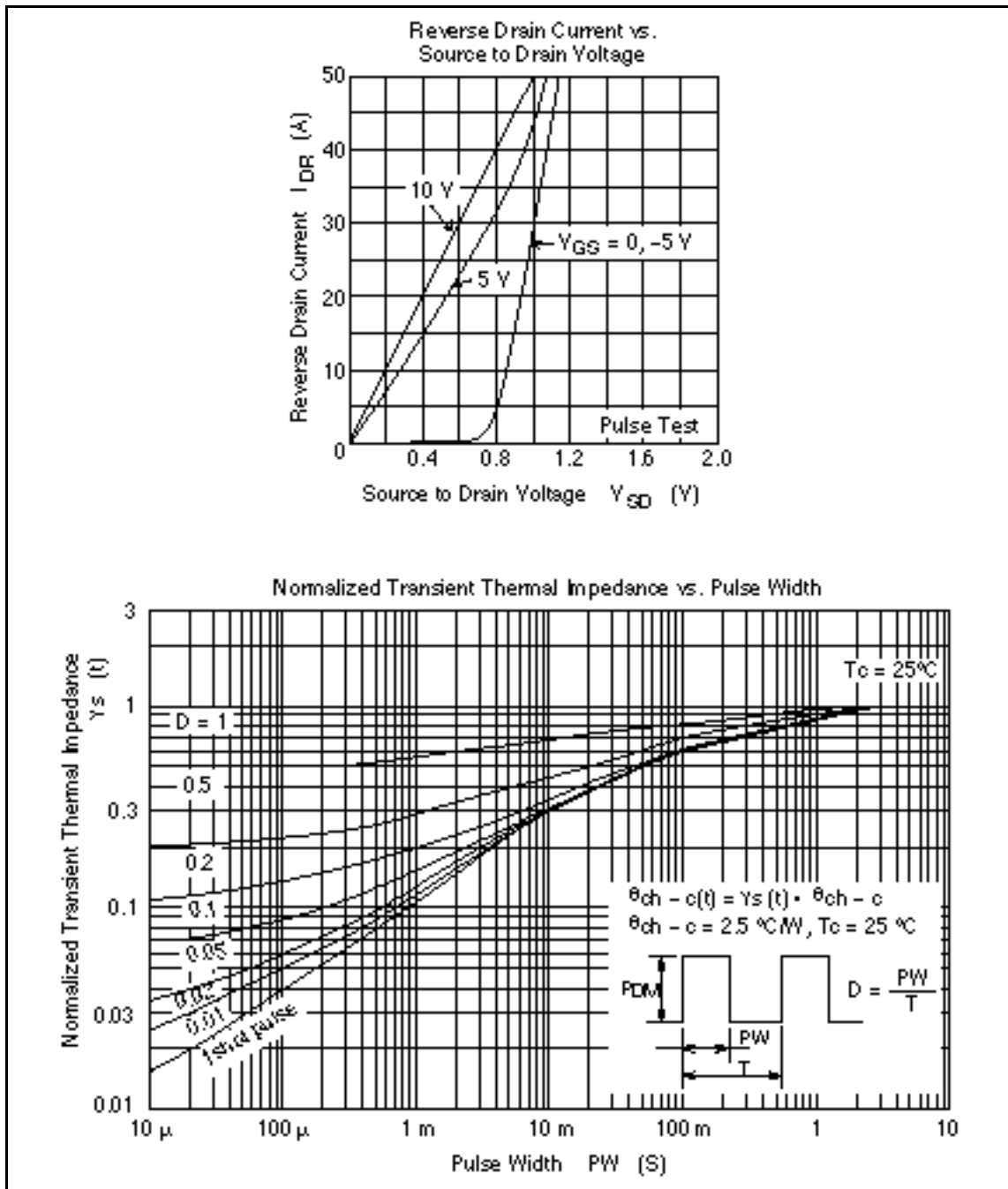
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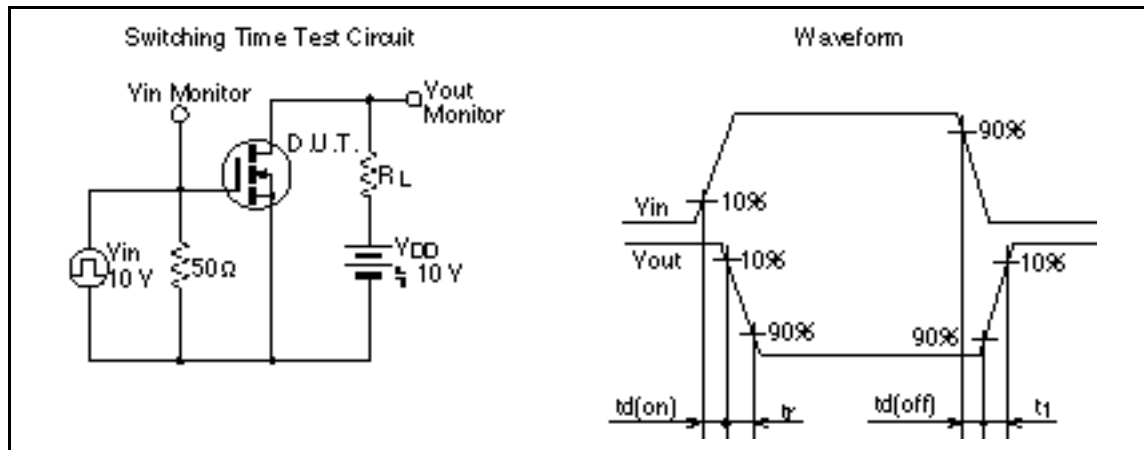
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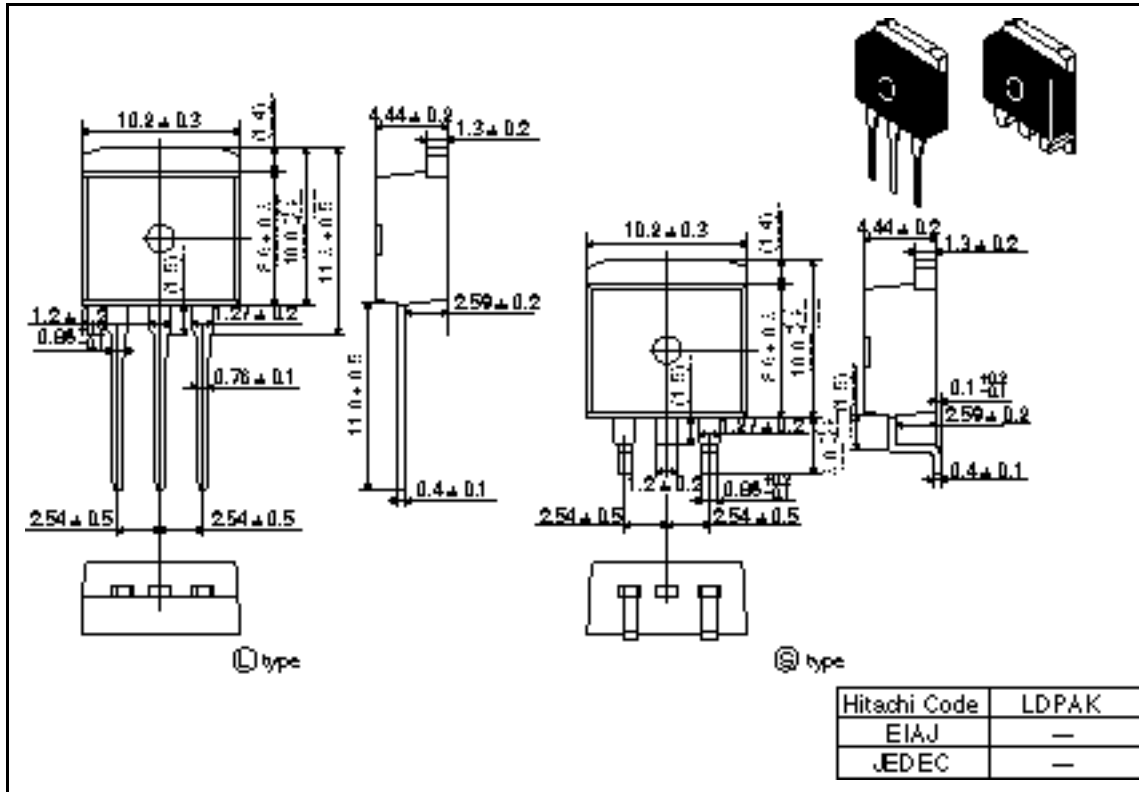
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Package Dimensions

Unit: mm



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HITACHI

Hitachi, Ltd.

Semiconductor & IC Div.

Nippon Bldg., 2-6-2, Ohia-machi, Chiyoda-ku, Tokyo 100, Japan

Tel Tokyo (03) 3270-2111

Fax (03) 3270-5109

For further information write to:

Hitachi America, Ltd.

Semiconductor & IC Div.

2000 Sierra Point Parkway

Brea, CA, 94005-4935

U.S.A.

Tel 415-589-8300

Fax 415-589-4207

Hitachi Europe GmbH

Electronic Components Group

Continental Europe

Dornacher Straße 3

D-85632 Feldkirchen

München

Tel 089-9 91 80-0

Fax 089-9 29 30 00

Hitachi Europe Ltd.

Electronic Components Div.

Northern Europe Headquarters

Whitebrook Park

Lower Cookham Road

Midlehead

Berkshire SL6 5YA

United Kingdom

Tel 0628-585000

Fax 0628-778322

Hitachi Asia Pte. Ltd.

#6 Collyer Quay #20-00

Hitachi Tower

Singapore 0404

Tel 535-2100

Fax 535-1533

Hitachi Asia (Hong Kong) Ltd.

Unit 706, North Tower,

World Finance Centre

Harbour City, Canton Road

Tsim Sha Tsui, Kowloon

Hong Kong

Tel 27359218

Fax 27308074

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